## NSN 5961-01-400-2444

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-400-2444 **Inclosure Material:** Metal **Overall Length:** Between 1.022 inches and 1.253 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches Thready Qty Per Inch (tpi): 32 **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 400.00 amperes collector current, dc preset **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 81349-mil-s-19500/478 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: